IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Takenori GOTO, et al.

Serial Number: 09/532,791

Filed: March 22, 2000

Group Art Unit: 2874

Attention: Appln Processing Division,

Customer Correction Branch

For:

SEMICONDUCTOR LASER DEVICE AND METHOD OF FABRICATING THE

SAME

REQUEST FOR CORRECTED FILING RECEIPT

Director of Patents & Trademarks Washington, D.C. 20231

Date: July 10, 2000

Sir:

Please supply the undersigned attorney with a corrected filing receipt for the aboveidentified application. The undersigned also respectfully requests that the Patent and Trademark Office records be amended to reflect the correction.

In reviewing the official Filing Receipt, we noted an error in that there is a typographical error in the title ("SEMICONDUTOR" should read - -SEMICONDUCTOR- -). A copy of the Declaration is enclosed which indicates the correct spelling.

We are enclosing a copy of the filing receipt with the correction highlighted.

In the event that any fees are required in connection with this paper, please charge our Deposit Account No. 01-2340.

Respectfully submitted,

ARMSTRONG, WESTERMAN, HATTORI, McLELAND & NAUGHTON

> William G. Kratz^UJr. Attorney for Applicants Reg. No. 22,631

Atty. Docket No. 000350 1725 K Street, N.W., Suite 1000 Washington, DC 20006 Tel: (202) 659-2930 Fax: (202) 887-0357

Enclosures: Copies of Filing Receipt & Declaration



FILING RECEIPT *OC000000005140289*



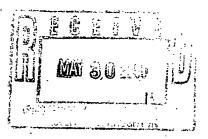
UNITED STATES DEPARTMENT OF COMMERCE Patent and Trademark Office

Address: ASSISTANT SECRETARY AND

COMMISSIONER OF PATENT AND TRADEMARKS Washington, D.C. 20231

APPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTY.DOCKET.NO	DRAWINGS	TOT CLAIMS	IND CLAIMS	
09/532,791	03/22/2000	2874	708	000350	16	21	2	

Armstrong Westerman Hattori Mcleland & Naughton 1725 K Street NW Suite 1000 Washington, DC 20006



Date Mailed: 05/25/2000

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the PTO processes the reply to the Notice, the PTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Takenori Goto, Moriguchi-shi, JAPAN; Nobuhiko Hayashi, Osaka-shi, JAPAN;

Continuing Data as Claimed by Applicant

Foreign Applications

JAPAN 11-79470 03/24/1999 JAPAN 2000-63271 03/08/2000

If Required, Foreign Filing License Granted 05/25/2000

AUG - 1 2000 TC 2800 MAIL BOOK

Title

Semiconductor

Semicondutor laser device and method of fabricating the same

Preliminary Class

372

Data entry by: DADE, JOAN

Team: OIPE

Date: 05/25/2000

DECLARATION FOR U.S. PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention **entitled**

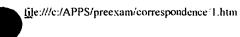
(Insert Title) S	EMICONDUCTOR I	ASER DEVICE	AND METHOD OF FABRIC	CATING THE SAME
the specification	on of which is attached	hereto unless the i	following is checked:	
	was filed on Application Number_ (if applicable).		uited States Application Numb and was amended on	per or PCT Internationa
-	that I have reviewed claim(s), as amended by		the contents of the above- referred to above.	identified specification
_	the duty to disclose in the duty to disclose in the disclose i		is material to the patentability	y as defined in Title 37
application(s)	for patent or inventor's c	's certificate listed	below and have also idential filing date before that of the	fied below any foreign
•				Priority Claimed
(List prior	11-79470	Japan	24/3/1999	_X_ Yes No
foreign	(Number)	(Country)	(Day/Month/Year Filed)	
applications.	_2000-63271	Japan	8/3/2000	_X_ Yes No
See note A	(Number)	(Country)	(Day/Month/Year Filed)	
on back of			•	Yes No
his page)	(Number)	(Country)	(Day/Month/Year Filed)	
(See note B on	back of this page)	See attached	list for additional prior foreig	n applications
hereby claim application(s) l		le 35, United Stat	es Code, § 119(e) of any Ui	nited States provisional
	(Application	Number)	(Filing Date)	

(Filing Date)

(Application Number)









Bib Data Sheet



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Patent and Trademark Office

Address: COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231

SERIAL NUMBI 09/532,791	1 03/22/2000 1		1	GROUP ART UNIT 2874			ATTORNEY DOCKET NO. 000350		
APPLICANTS Takenori Goto, Moriguchi-shi, JAPAN; Nobuhiko Hayashi, Osaka-shi, JAPAN; ** CONTINUING DATA **********************************									
IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 05/25/2000 - Foreign Priority claimed									
ADDRESS — Armstrong Westerman Hattori Mcleland & Naughton 1725 K Street NW Suite 1000 Washington ,DC 20006 TITLE									
Semiconductor laser device and method of fabricating the same									
RECEIVED				•	TNU	All Fees 1.16 Fees (Filing) 1.17 Fees (Processing Ext. time) 1.18 Fees (Issue) Other Credit			essing Ext. of